

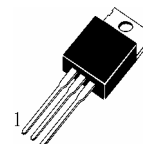
30A SCHOTTKY BARREIER RECTIFIER

Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Power Loss,High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- For Use in Low Voltage,High Frequency Inverters,Free Wheelings, and Polarity Protection Applications

Package

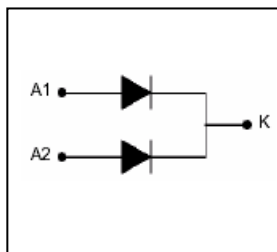
TO-220



1—Pin A1
2—Pin K
3—Pin A2

Maximum Ratings

- T_{stg} ——Storage Temperature.....-65~150℃
- T_j ——Operating Temperature.....-65~150℃
- V_{RRM} ——Peak Repetitive Reverse Voltage.....40V
- V_{RWM} ——Working Peak Reverse Voltage.....40V
- V_R ——DC Blocking Voltage.....40V
- $V_{R(RMS)}$ ——RMS Reverse Voltage.....28V
- $I_F(AV)$ ——Average Recified Output Current@ $T_c=95^{\circ}C$ Double Dies 30A
◆ (Note 1)Single Die 15A
- I_{FSM} ——Non-Repetitive Peak Forward Surge Current (Single Die, 60Hz)250A



Electrical Chatacteristic@ $T_a=25^{\circ}C$ unless otherwise specified

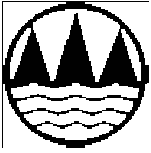
Single phase,half wave,60Hz,resistive or inductive load.

For capacitive load,derate current by 20%.

Characteristic	Symbol	Min	Max	Unit	Condition
Forward Voltage Drop	V_{FM}		0.55	V	$I_F=15A, T_C=25^{\circ}C$
Peak Reverse Current at Rated DC Blocking Voltage	I_{RM}		1.0 75	mA	$V_R = V_{RRM} \quad T_C=25^{\circ}C$ $T_C=100^{\circ}C$
Typical Junction Capacitance(Note 2)	C_j		1100	pF	
Typical Thermal Resistance Junction to Case(Note 1)	R_{th-j}		2.0	°C/W	

Notes:1、 Thermal resistance junction to case mounted on heatsink.

2、 Measured at 1.0 MHz and Applied Reverse Voltage of 4.0V DC.



PERFORMANCE CURVES

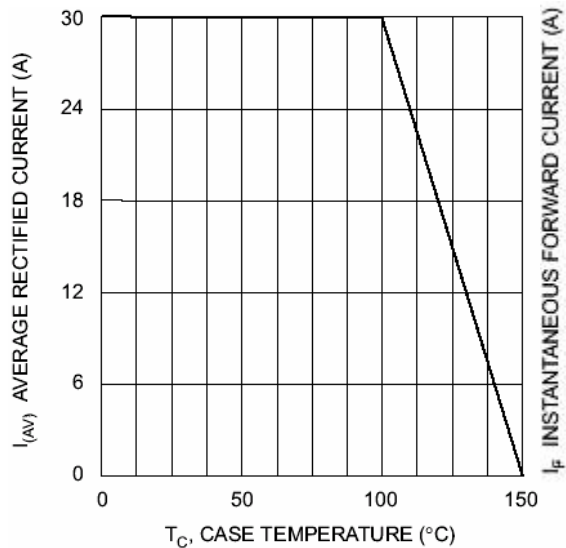


Fig. 1 Forward Derating Curve

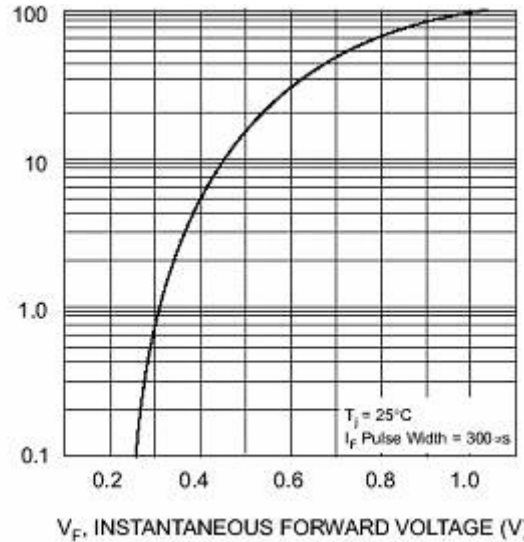


Fig. 2 Typical Forward Characteristics

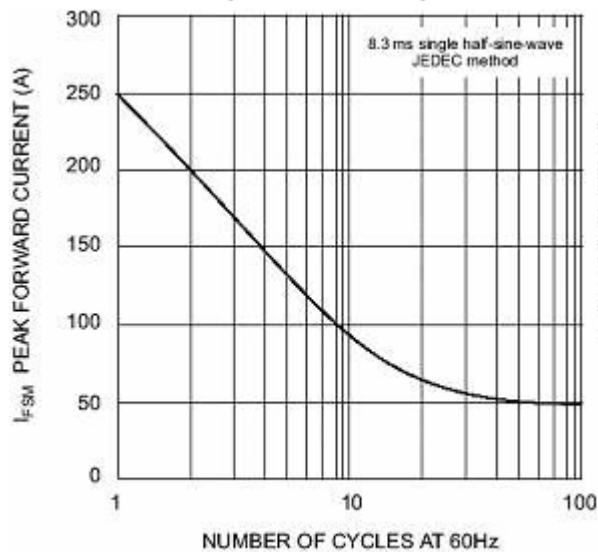


Fig. 3 Maximum Non-Repetitive Surge Current

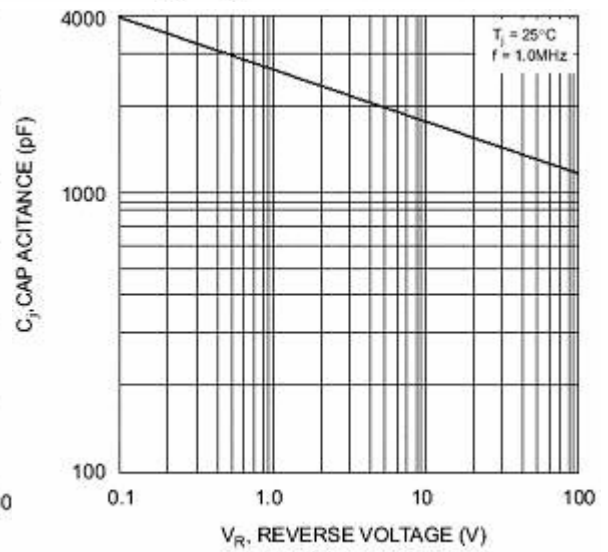


Fig. 4 Typical Junction Capacitance